

## Spin orbit torques and Dzyaloshinskii-Moriya interaction induced chiral spin structures

Motivation: Current storage and logic devices are reaching their intrinsic limits. Magnetic memory devices are a promising technology to overcome these limits. However, the manipulation of magnetization is a key to development of these new technologies. The spin orbit torque and Dzyaloshinskii-Moriya interaction induced chiral spin structures are potential keys in efficient magnetization switching.



## Bachelor and Master Thesis in the group of Prof Kläui

Contact: Prof. Dr. Mathias Kläui

klaeui@uni-mainz.de

- System: Magnetic multilayer nanodevices with perpendicular magnetic anisotropy and spin orbit coupling.
- Experiments: Growth and characterization of magnetic multilayer thin films; Nanofabrication of spintronic devices; investigation of current-induced domain wall dynamics and magnetotransport.
- Techniques: magneto-sputtering system; Superconducting Quantum Interference Device (SQUID); Electron-beam lithography; Magneto-optical Kerr effect (MOKE); Kerr microscopy; Transport measurements in magnetic vector-coil cryostat; Micromagnetic simulations.

Horizon 2020

Prooramme

